NSN 5961-01-541-1980

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Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-541-1980 **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **End Application:** Radar 3d e/f band, long range **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.016 inches and 0.021 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 4.00 amperes all primaries **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: